## NSN 5962-01-317-4145

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.925 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power D	issipation Rating:
409.6 milliwatts	
Operating Tempura	ature Range:
-55.0/+125.0 degree	
Storage Tempurati	ire Range:
-65.0/+150.0 degree	us celsius
Features Provided	
Monolithic and bipol	ar and 3-state output
Inclosure Material:	
Ceramic	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patter	n:
8 input	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	d Type Per Characteristic:
7.0 volts power sou	rce
Memory Device Ty	pe:
Rom	
Test Data Docume	nt:
96906-mil-std-883 s	tandard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	Quantity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	